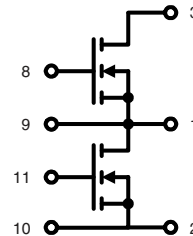


Dual Trench MOSFET Module

Phaseleg Configuration

$$\begin{aligned} V_{DSS} &= 100 \text{ V} \\ I_{D25} &= 1000 \text{ A} \\ R_{DS(on)} &= 0.75 \text{ m}\Omega \end{aligned}$$

Preliminary data



MOSFET T1 + T2				
Symbol	Conditions	Maximum Ratings		
V_{DSS}	$T_{VJ} = 25^{\circ}\text{C to } 150^{\circ}\text{C}$	100	V	
V_{GS}		± 20	V	
I_{D25}	$T_C = 25^{\circ}\text{C}$ ①	1000	A	
I_{D80}	$T_C = 80^{\circ}\text{C}$ ①	800	A	
I_{F25}	(diode) $T_C = 25^{\circ}\text{C}$ ①	1000	A	
I_{F80}	(diode) $T_C = 80^{\circ}\text{C}$ ①	800	A	

Symbol	Conditions	Characteristic Values ($T_{VJ} = 25^{\circ}\text{C}$, unless otherwise specified)		
		min.	typ.	max.
R_{DSon}	$V_{GS} = 10 \text{ V}; I_D = I_{D80}$		0.75	1.2 m Ω
V_{GSth}	$V_{DS} = 20 \text{ V}; I_D = 10 \text{ mA}$	2		4 V
I_{DSS}	$V_{DS} = V_{DSS}; V_{GS} = 0 \text{ V}; T_{VJ} = 25^{\circ}\text{C to } 125^{\circ}\text{C}$		1.5	0.15 mA
I_{GSS}	$V_{GS} = \pm 20 \text{ V}; V_{DS} = 0 \text{ V}$			1.5 μA
Q_g Q_{gs} Q_{gd}	$V_{GS} = 10 \text{ V}; V_{DS} = 80 \text{ V}; I_D = 1000 \text{ A}$		2355 495 1000	nC nC nC
$t_{d(on)}$ t_r $t_{d(off)}$ t_f	$V_{GS} = 10 \text{ V}; V_{DS} = 50 \text{ V}; I_D = 250 \text{ A}; R_G = 0.68 \Omega$		50 100 260 100	ns ns ns ns
V_F	(diode) $I_F = 500 \text{ A}; V_{GS} = 0 \text{ V}$		1.0	1.5 V
t_{rr}	(diode) $I_F = 200 \text{ A}; -di/dt = 1000 \text{ A}/\mu\text{s}; V_{DS} = 30 \text{ V}$		100	ns
R_{thJC} R_{thJS}	with heat transfer paste		0.12	0.06 K/W K/W

① additional current limitation by external leads

Features

- Trench MOSFETs
 - low R_{DSon}
 - optimized intrinsic reverse diode
- package
 - low inductive current path
 - screw connection to high current main terminals
 - use of non interchangeable connectors for auxiliary terminals possible
 - Kelvin source terminals for easy drive
 - isolated DCB ceramic base plate

Applications

- converters with high power density for
 - main and auxiliary AC drives of electric vehicles
 - 4 quadrant DC drives
- power supplies with low input voltage, e.g. from fuel cells or solar cells

IXYS reserves the right to change limits, test conditions and dimensions.

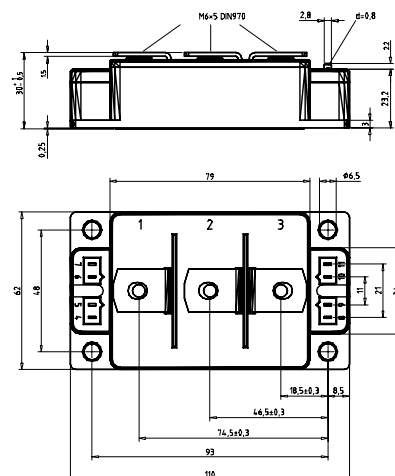
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Module

Symbol	Conditions	Maximum Ratings	
I_{RMS}	per main terminal	500	A
T_{VJ}		-40...+175	°C
T_{stg}		-40...+125	°C
V_{ISOL}	$I_{ISOL} \leq 1 \text{ mA}; 50/60 \text{ Hz}$	3600	V~
M_d	Mounting torque (M6)	2.25 - 2.75	Nm
	Terminal connection torque (M6)	4.5 - 5.5	Nm

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
Weight			250	g

Dimensions in mm (1 mm = 0.0394")



Optional accessories for modules

keyed twin plugs
(UL758, style 1385, CSA class 5851,
guide 460-1-1)

- Type ZY180L with wire length 350mm
– for pins 4 (yellow wire) and 5 (red wire)
– for pins 11 (yellow wire) and 10 (red wire)
- Type ZY180R with wire length 350mm
– for pins 7 (yellow wire) and 6 (red wire)
– for pins 8 (yellow wire) and 9 (red wire)

PHASE-OUT